

Clock Recovery and Data Retiming Phase-Locked Loop

AD800/AD802*

FEATURES

Standard Products 44.736 Mbps—DS-3 51.84 Mbps—STS-1 155.52 Mbps—STS-3 or STM-1

Accepts NRZ Data, No Preamble Required
Recovered Clock and Retimed Data Outputs
Phase-Locked Loop Type Clock Recovery—No Crystal

Required

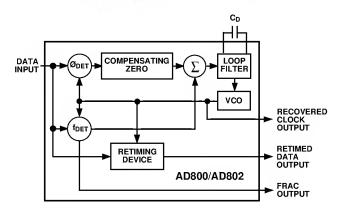
Random J itter: 20° Peak-to-Peak Pattern J itter: Virtually Eliminated

10KH ECL Compatible

Single Supply Operation: -5.2 V or +5 V

Wide Operating Temperature Range: -40°C to +85°C

FUNCTIONAL BLOCK DIAGRAM



PRODUCT DESCRIPTION

The AD 800 and AD 802 employ a second order phase-locked loop architecture to perform clock recovery and data retiming on Non-Return to Zero, NRZ, data. This architecture is capable of supporting data rates between 20 M bps and 160 M bps. The products described here have been defined to work with standard telecommunications bit rates. 45 M bps DS-3 and 52 M bps STS-1 are supported by the AD 800-45 and AD 800-52 respectively. 155 M bps STS-3 or STM-1 are supported by the AD 802-155.

U nlike other PLL-based clock recovery circuits, these devices do not require a preamble or an external VCXO to lock onto input data. The circuit acquires frequency and phase lock using two control loops. The frequency acquisition control loop initially acquires the clock frequency of the input data. The phase-lock loop then acquires the phase of the input data, and ensures that the phase of the output signals track changes in the phase of the input data. The loop damping of the circuit is dependent on the value of a user selected capacitor; this defines jitter peaking performance and impacts acquisition time. The devices exhibit 0.08 dB jitter peaking, and acquire lock on random or scrambled data within 4×10^5 bit periods when using a damping factor of 5.

During the process of acquisition the frequency detector provides a Frequency Acquisition (FRAC) signal which indicates that the device has not yet locked onto the input data. This signal is a series of pulses which occur at the points of cycle slip between the input data and the synthesized clock signal. Once the circuit has acquired frequency lock no pulses occur at the FRAC output.

The inclusion of a precisely trimmed VCO in the device eliminates the need for external components for setting center frequency, and the need for trimming of those components. The VCO provides a clock output within $\pm 20\%$ of the device center frequency in the absence of input data.

The AD 800 and AD 802 exhibit virtually no pattern jitter, due to the performance of the patented phase detector. Total loop jitter is 20° peak-to-peak. Jitter bandwidth is dictated by mask programmable fractional loop bandwidth. The AD 800, used for data rates < 90 M bps, has been designed with a nominal loop bandwidth of 0.1% of the center frequency. The AD 802, used for data rates in excess of 90 M bps, has a loop bandwidth of 0.08% of center frequency.

All of the devices operate with a single +5 V or -5.2 V supply.

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AD800/AD802- SPECIFICATIONS $(V_{EE} = V_{MIN} \text{ to } V_{MAX}, V_{CC} = GND, T_A = T_{MIN} \text{ to } T_{MAX}, Loop Damping Factor = 5, unless otherwise noted)}$

| Parameter ¹ | Condition | AD Min | 800-45 Typ | BQ Max | Al Min | D800-52 Typ | 2BR Max | AD8 | 102- 155 Typ | CR/BR Max | Units |
|---|--|---------------------|--|------------------------|--------------------------|---|------------------------|-----------------|--|------------------------|---|
| NOMINAL CENTER FREQUEN | CY | | 44.736 | 5 | | 51.84 | | | 155.52 | <u> </u> | MHz |
| OPERATING TEMPERATURE RANGE (T _{MIN} to T _{MAX}) | K Grade B Grade | -40 | | 85 | -40 | | 85 | 0 -40 | | 70 85 | °C °C |
| TRACKING RANGE | | 43 | | 45.5 | 49 | | 53 | 155 | | 156 | M bps |
| CAPTURE RANGE | | 43 | | 45.5 | 49 | | 53 | 155 | | 156 | M bps |
| STATIC PHASE ERROR | $\rho = 1$, $T_A = +25^{\circ}C$, $V_{EE} = -5.2 \text{ V}$ $\rho = 1$ | | 2 3 | 10 11.5 | | 2 3 | 10 11.5 | | 14 18 | 30 37 | D egrees D egrees |
| RECOVERED CLOCK SKEW | t _{RCS} (Figure 1) | 0.2 | 0.6 | 1 | 0.2 | 0.6 | 1 | 0.2 | 8.0 | 1 | ns |
| SETUPTIME | t _{SU} (Figure 1) | | | | | | | 2.06 | 2.37 | | ns |
| TRANSITIONLESS DATA RUN | | | | 240 | | | 240 | | | 240 | Bit Periods |
| OUTPUT JITTER | $\rho = 1$ 2 ⁷ -1 PRN Sequence 2 ²³ -1 PRN Sequence | | 2 2.5 2.5 | 4.7 4.7 | | 2 2.5 2.5 | 4.7 4.7 | | 3.5 5.4 5.4 | 9.7 9.7 | D egrees rms D egrees rms D egrees rms |
| JITTER TOLERANCE | f = 10 Hz f = 2.3 kHz f = 30 kHz f = 1 M Hz f = 30 Hz f = 300 Hz f = 2 kHz f = 20 kHz f = 65 kHz f = 65 kHz | 6.5 0.47 0.47 | 2,500 | | 830 83 7.4 0.47 | 2,500 | | 2.0 0.26 | 7.6 0.9 | | U nit Intervals |
| JITTER TRANSFER Damping Factor Capacitor, C_D $\zeta=1$, Nominal $\zeta=5$, Nominal $\zeta=10$, Nominal Peaking $\zeta=1$, Nominal $\zeta=5$, Nominal $\zeta=5$, Nominal $\zeta=10$, Nominal Bandwidth | T _A = +25°C, V _{EE} = -5.2 V T _A = +25°C, V _{EE} = -5.2 V T _A = +25°C, V _{EE} = -5.2 V | | 8.2 0.22 0.82 2 0.08 0.02 45 | | | 6.8 0.15 0.68 2 0.08 0.02 52 | | | 2.2 0.047 0.22 2 0.08 0.02 130 | | nF μF μF dB dB dB kHz |
| ACQUISITION TIME $ \rho = 1/2 \\ T_A = +25^{\circ}C \\ V_{EE} = -5.2 \text{ V} $ | $ \zeta = 1 \zeta = 5 \zeta = 10 $ | | 1×10 3×10 8×10 | $^{5} 8 \times 10^{5}$ | | 1×10^{4} 3×10^{5} 8×10^{5} | 5 8 $	imes$ 10 5 | | 1.5 × 1 4 × 10 1.4 × 1 | $^{5} 8 \times 10^{5}$ | Bit Periods Bit Periods Bit Periods |
| POWER SUPPLY Voltage (V _{MIN} to V _{MAX}) Current | $T_A = +25^{\circ}C$ $T_A = +25^{\circ}C$, $V_{EE} = -5.2 \text{ V}$ | -4.5 | -5.2 125 | -5.5 170 180 | -4.5 | -5.2 125 | -5.5 170 180 | -4.5 | -5.2 140 | -5.5 180 205 | Volts mA mA |
| INPUT VOLTAGE LEVELS Input Logic High, V _{IH} Input Logic Low, V _{IH} | T _A = +25°C | -1.084 -1.95 | | -0.72 -1.594 | -1.084 -1.95 | | -0.72 -1.594 | -1.084 -1.95 | | -0.72 -1.594 | Volts Volts |
| OUTPUT VOLTAGE LEVELS Output Logic High, V _{OH} Output Logic Low, V _{OL} | T _A = +25°C | -1.084 -1.95 | | -0.72 -1.60 | -1.084 -1.95 | | -0.72 -1.60 | -1.084 -1.95 | | -0.72 -1.60 | Volts Volts |
| INPUT CURRENT LEVELS Input Logic High, I _{IH} Input Logic Low, I _{IL} | T _A = +25°C | | | 125 80 | | | 125 80 | | | 125 80 | μΑ μΑ |
| OUTPUT SLEW TIMES Rise Time (t_R) Fall Time (t_F) | T _A = +25°C 20%-80% 80%-20% | | 0.75 0.75 | 1.5 1.5 | | 0.75 0.75 | 1.5 1.5 | | 0.75 0.75 | 1.5 1.5 | ns ns |
| SYMMETRY Recovered Clock Output | $\rho = 1/2$, $T_A = +25$ °C $V_{EE} = -5.2$ V | 45 | | 55 | 45 | | 55 | 45 | | 55 | % |

Specifications subject to change without notice.

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 $^{{}^{1}\}textrm{R}\,\textrm{efer}$ to Glossary for parameter definition.

ABSOLUTE MAXIMUM RATINGS*

| Supply Voltage |
|--|
| Input Voltage (Pin 16 or Pin 17 to V_{CC}) V_{EE} to +300 mV |
| M aximum Junction T emperature |
| SOIC Package+150°C |
| Ceramic DIP Package+175°C |
| Storage T emperature Range65°C to +150°C |
| L ead T emperature Range (Soldering 60 sec) +300°C |
| ESD Rating |
| AD800 1500 V |
| AD 802 1000 V |
| and the state of t |

*Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to an absolute maximum rating condition for an extended period may adversely affect device reliability.

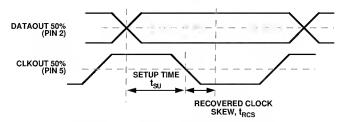


Figure 1. Recovered Clock Skew and Setup (See Previous Page)

PIN DESCRIPTIONS

| Number | Mnemonic | Description |
|--------|------------------|-------------------------------------|
| 1 | DATAOUT | Differential Retimed Data Output |
| 2 | DATAOUT | Differential Retimed Data Output |
| | V_{CC2} | Digital Ground |
| 4 | CLKOUT | Differential Recovered Clock Output |
| 5 | CLKOUT | Differential Recovered Clock Output |
| 6 | V _{EE} | Digital V _{EE} |
| 7 | V _{EE} | Digital V _{EE} |
| 8 | V _{CC1} | Digital Ground |
| 9 | AVEE | Analog V _{EE} |
| 10 | ASUBST | Analog Substrate |
| 11 | CF ₂ | Loop Damping Capacitor Input |
| 12 | CF ₁ | Loop Damping Capacitor Input |
| 13 | AV _{cc} | Analog Ground |
| 14 | V _{CC1} | Digital Ground |
| 15 | V _{EE} | Digital V _{EE} |
| 16 | DATAIN | Differential Data Input |
| 17 | DATAIN | Differential Data Input |
| 18 | SUBST | Digital Substrate |
| 19 | FRAC | Differential Frequency Acquisition |
| | | Indicator Output |
| 20 | FRAC | Differential Frequency Acquisition |
| | | Indicator Output |

THERMAL CHARACTERISTICS

| | θις | θ_{JA} |
|----------------|--------|---------------|
| SOIC Package | 22°C/W | 75°C/W |
| Cerdip Package | 25°C/W | 90°C/W |

Use of a heatsink may be required depending on operating environment

GLOSSARY

Maximum and Minimum Specifications

M aximum and minimum specifications result from statistical analyses of measurements on multiple devices and multiple test systems. T ypical specifications indicate mean measurements. M aximum and minimum specifications are calculated by adding or subtracting an appropriate guardband from the typical specification. D evice-to-device performance variation and test system-to-test system variation contribute to each guardband.

Nominal Center Frequency

This is the frequency that the VCO will operate at with no input signal present and the loop damping capacitor, C_D, shorted.

Tracking Range

This is the range of input data rates over which the PLL will remain in lock.

Capture Range

This is the range of input data rates over which the PLL can acquire lock.

Static Phase Error

This is the steady-state phase difference, in degrees, between the recovered clock sampling edge and the optimum sampling instant, which is assumed to be halfway between the rising and falling edges of a data bit. Gate delays between the signals that define static phase error, and IC input and output signals prohibit direct measurement of static phase error.

Data Transition Density, p

T his is a measure of the number of data transitions, from "0" to "1" and from "1" to "0," over many clock periods. ρ is the ratio $(0 \le \rho \le 1)$ of data transitions to clock periods.

litte

This is the dynamic displacement of digital signal edges from their long term average positions, measured in degrees rms, or Unit Intervals (UI). Jitter on the input data can cause dynamic phase errors on the recovered clock sampling edge. Jitter on the recovered clock causes jitter on the retimed data.

Output Jitter

This is the jitter on the retimed data, in degrees rms, due to a specific pattern or some psuedo-random input data sequence (PRN Sequence).

Jitter Tolerance

Jitter tolerance is a measure of the PLL's ability to track a jittery input data signal. Jitter on the input data is best thought of as phase modulation, and is usually specified in unit intervals.

ORDERING GUIDE

| Device | Center Frequency | Fractional Loop Bandwidth | Description | Operating Temperature | Package Option |
|---------------|------------------|------------------------------|---------------------|-----------------------|----------------|
| AD 800-45BQ | 44.736 M H z | 0.1% | 20-Pin Cerdip | -40°C to +85°C | Q-20 |
| AD 800-52BR | 51.84 M H z | 0.1% | 20-Pin Plastic SOIC | -40°C to +85°C | R-20 |
| AD 802-155BR | 155.52 M H z | 0.08% | 20-Pin Plastic SOIC | -40°C to +85°C | R-20 |
| AD 802-155K R | 155.52 M H z | 0.08% | 20-Pin Plastic SOIC | 0°C to +70°C | R-20 |

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The PLL must provide a clock signal which tracks this phase modulation in order to accurately retime jittered data. In order for the VCO output to have a phase modulation which tracks the input jitter, some modulation signal must be generated at the output of the phase detector (see Figure 21). The modulation output from the phase detector can only be produced by a phase error between the data input and the clock input. Hence, the PLL can never perfectly track jittered data. However, the magnitude of the phase error depends on the gain around the loop. At low frequencies the integrator provides very high gain, and thus very large jitter can be tracked with small phase errors between input data and recovered clock. At frequencies closer to the loop bandwidth, the gain of the integrator is much smaller, and thus less input jitter can be tolerated. The PLL data output will have a bit error rate less than 1×10^{-10} when in lock and retiming input data that has the specified jitter applied to it.

Jitter Transfer

The PLL exhibits a low-pass filter response to jitter applied to its input data.

Bandwidth

This describes the frequency at which the PLL attenuates sinusoidal input jitter by 3 dB.

Peaking

This describes the maximum jitter gain of the PLL in dB.

Damping Factor, ζ

 ζ describes how the PLL will track an input signal with a phase step. A greater value of ζ corresponds to less overshoot in the PLL response to a phase step. ζ is a standard constant in second order feedback systems.

Acquisition Time

This is the transient time, measured in bit periods, required for the PLL to lock on input data from its free-running state.

Symmetry

Symmetry is calculated as ($100 \times \text{on time}$)/period, where on time equals the time that the clock signal is greater than the midpoint between its "0" level and its "1" level.

Bit Error Rate vs. Signal-to-Noise Ratio

The AD 800 and AD 802 were designed to operate with standard ECL signal levels at the data input. Although not recommended, smaller input signals are tolerable. Figure 8, 14, and 20 show the bit error rate performance versus input signal-tonoise ratio for input signal amplitudes of full 900 mV ECL, and decreased amplitudes of 80 mV and 20 mV. Wideband amplitude noise is summed with the data signals as shown in Figure 2. The full ECL and 80 mV signals give virtually indistinguishable results. The 20 mV signals also provide adequate performance when in lock, but signal acquisition may be impaired.

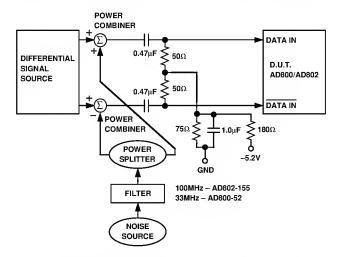


Figure 2. Bit Error Rate vs. Signal-to-Noise Ratio Test: Block Diagram

USING THE AD800 AND THE AD802 SERIES Ground Planes

Use of one ground plane for connections to both analog and digital grounds is recommended. Output signal sensitivity to power supply noise (PECL configuration, Figure 22) is less using one ground plane than when using separate analog and digital ground planes.

Power Supply Connections

U se of a $10\,\mu\bar{\text{F}}$ tantalum capacitor between V_{EE} and ground is recommended.

U se of $0.1~\mu\text{F}$ ceramic capacitors between IC power supply or substrate pins and ground is recommended. Power supply decoupling should take place as close to the IC as possible. Refer to schematics, Figure 22 and Figure 26, for advised connections.

Sensitivity of IC output signals (PECL configuration, Figure 22) to high frequency power supply noise (at 2 \times the nominal data rate) can be reduced through the connection of signals AV $_{\rm CC}$ and V $_{\rm CC1}$, and the addition of a bypass network. The type of bypass network to consider depends on the noise tolerance required. The more complex bypass network schemes tolerate greater power supply noise levels. Refer to Figures 23 and 24 for bypassing schemes and power supply sensitivity curves.

Transmission Lines

U se of 50 Ω transmission lines are recommended for DATAIN , CLKOUT, DATAOUT, and FRAC signals.

Terminations

T ermination resistors should be used for DATAIN, CLKOUT, DATAOUT, and FRAC signals. Metal, thick film, 1% tolerance resistors are recommended. T ermination resistors for the DATAIN signals should be placed as close as possible to the DATAIN pins.

Connections from V_{EE} to lead resistors for DATAIN, DATA-OUT, FRAC, and CLKOUT signals should be individual, not daisy chained. This will avoid crosstalk on these signals.

Loop Damping Capacitor, C_D

A ceramic capacitor may be used for the loop damping capacitor.

Input Buffer

U se of an input buffer, such as a 10H 116 Line Receiver IC, is suggested for an application where the DATAIN signals do not come directly from an ECL gate, or where noise immunity on the DATAIN signals is an issue.

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Typical Characteristics- AD800/AD802

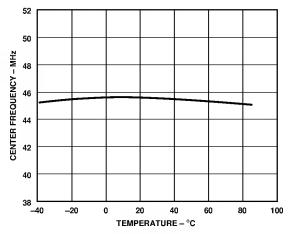


Figure 3. AD800-45 Center Frequency vs. Temperature

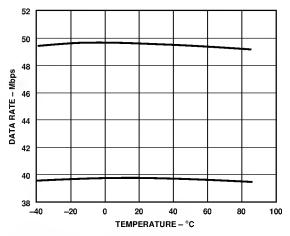


Figure 5. AD800-45 Capture and Tracking Range vs. Temperature

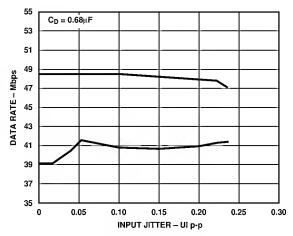


Figure 7. AD800-45 Acquisition Range vs. Input J itter

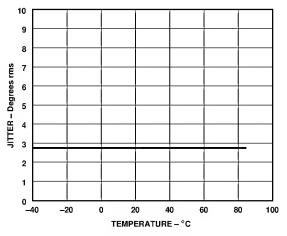


Figure 4. AD800-45 J itter vs. Temperature

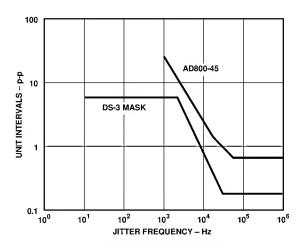


Figure 6. AD800-45 J itter Tolerance

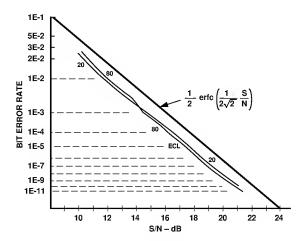


Figure 8. AD800-45 Bit Error Rate vs. Input J itter

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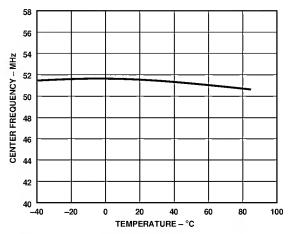


Figure 9. AD800-52 Center Frequency vs. Temperature

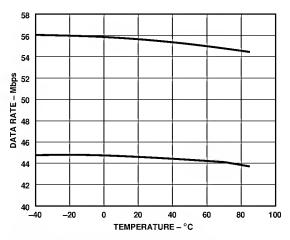


Figure 11. AD800-52 Capture and Tracking Range vs. Temperature

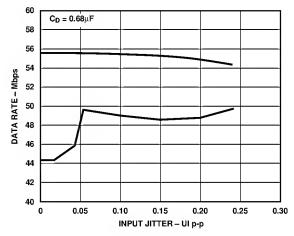


Figure 13. AD800-52 Acquisition Range vs. Input J itter

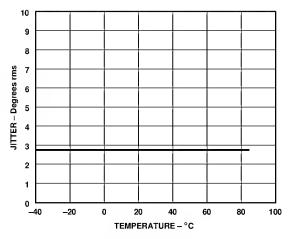


Figure 10. AD800-52 J itter vs. Temperature

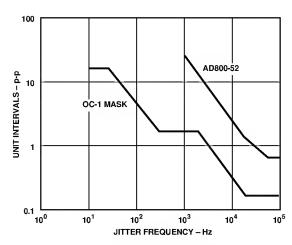


Figure 12. AD800-52 J itter Tolerance

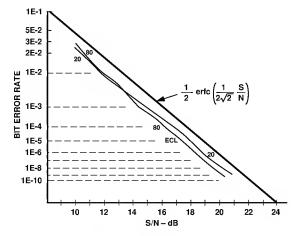


Figure 14. AD800-52 Bit Error Rate vs. Input J itter

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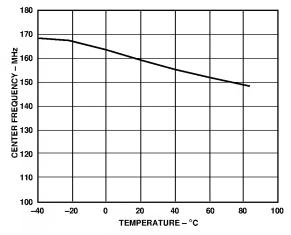
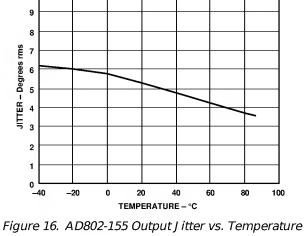


Figure 15. AD802-155 Center Frequency vs. Temperature



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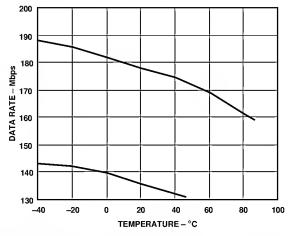


Figure 17. AD802-155 Capture Range, Tracking Range vs. Temperature

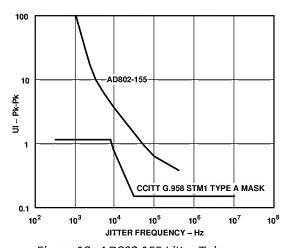


Figure 18. AD802-155 J itter Tolerance

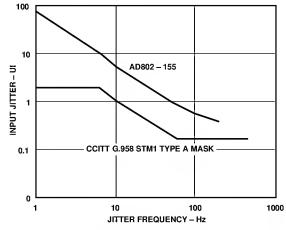


Figure 19. AD802-155 Minimum Acquisition Range vs. J itter Frequency, T_{MIN} to T_{MAX} V_{MIN} to V_{MAX}

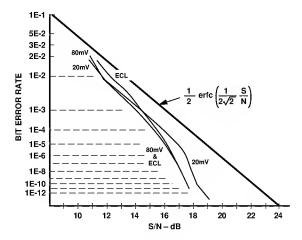


Figure 20. AD802-155 Bit Error Rate vs. Input J itter

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THEORY OF OPERATION

The AD 800 and AD 802 are phase-locked loop circuits for recovery of clock from NRZ data. The architecture uses a frequency detector to aid initial frequency acquisition, refer to Figure 21 for a block diagram. Note the frequency detector is always in the circuit. When the PLL is locked, the frequency error is zero and the frequency detector has no further effect. Since the frequency detector is always in circuit, no control functions are needed to initiate acquisition or change mode after acquisition. The frequency detector also supplies a frequency acquisition (FRAC) output to indicate when the loop is acquiring lock. During the frequency acquisition process the FRAC output is a series of pulses of width equal to the period of the VCO. These pulses occur on the cycle slips between the data frequency and the VCO frequency. With a maximum density (1010 . . .) data pattern, every cycle slip will produce a pulse at FRAC. However, with random data, not every cycle slip produces a pulse. The density of pulses at FRAC increases with the density of data transitions. The probability that a cycle slip will produce a pulse increases as the frequency error approaches zero. After the frequency error has been reduced to zero, the FRAC output will have no further pulses. At this point the PLL begins the process of phase acquisition, with a settling time of roughly 2000 bit periods. Valid retimed data can be guaranteed by waiting 2000 bit periods after the last FRAC pulse has occurred.

Jitter caused by variations of density of data transitions (pattern jitter) is virtually eliminated by use of a new phase detector (patented). Briefly, the measurement of zero phase error does not cause the VCO phase to increase to above the average run rate set by the data frequency. The jitter created by a 2^7 –1 pseudo-random code is 1/2 degree, and this is small compared to random jitter.

The jitter bandwidth for the AD 802-155 is 0.08% of the center frequency. This figure is chosen so that sinusoidal input jitter at 130 kHz will be attenuated by 3 dB. The jitter bandwidths of the AD 800-45 and AD 800-52 are 0.1% of the respective center frequencies. The jitter bandwidth of the AD 800 or the AD 802 is mask programmable from 0.01% to 1% of the center frequency. A device with a very low loop bandwidth (0.01% of the center frequency) could effectively filter (clean up) a jittery timing reference. Consult the factory if your application requires a special loop bandwidth.

The damping ratio of the phase-locked loop is user programmable with a single external capacitor. At 155 M Hz a damping ratio of 10 is obtained with a $0.22 \,\mu\text{F}$ capacitor. M ore generally,

the damping ratio scales as $1.7 \times \sqrt{f_{DATA} \times C_D}$. At 155 M H z a damping ratio of 1 is obtained with a 2.2 nF capacitor. A lower damping ratio allows a faster frequency acquisition; generally the acquisition time scales directly with the capacitor value. However, at damping ratios approaching one, the acquisition time no longer scales directly with the capacitor value. The acquisition time has two components: frequency acquisition and phase acquisition. The frequency acquisition always scales with capacitance, but the phase acquisition is set by the loop bandwidth of the PLL and is independent of the damping ratio. Thus, the 0.08% fractional loop bandwidth sets a minimum acquisition time of 15,000 bit periods. Note the acquisition time for a damping factor of 1 is specified as 15,000 bit periods. This comprises 13,000 bit periods for frequency acquisition and 2,000 periods for phase acquisition. Compare this to the 400,000 bit periods acquisition time specified for a damping ratio of 5; this consists entirely of frequency acquisition, and the 2,000 bit periods of phase acquisition is negligible.

While lower damping ratio affords faster acquisition, it also allows more peaking in the jitter transfer response (jitter peaking). For example, with a damping ratio of 10 the jitter peaking is 0.02 dB, but with a damping factor of 1, the peaking is 2 dB.

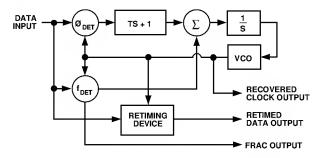


Figure 21. AD800 and AD802 Block Diagram

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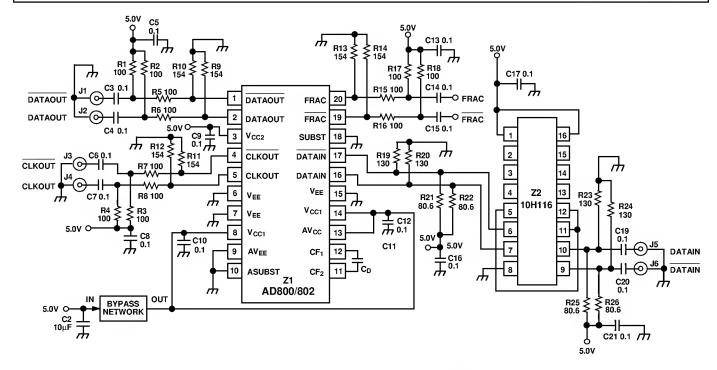


Figure 22. Evaluation Board Schematic, Positive Supply

Table I. Evaluation Board, Positive Supply: Components List

| Reference Designator | Description | Quantity |
|-------------------------|---|----------|
| R1-8, R15-18 | Resistor, 100 Ω, 1% | 12 |
| R9-14 | Resistor, 154 Ω , 1% | 6 |
| R19, 20, 23, 24 | Resistor, 130 Ω , 1% | 4 |
| R21, 22, 25, 26 | Resistor, 80.6Ω , 1% | 4 |
| CD | Capacitor, Loop Damping (See Specifications Page) | 1 |
| C 2 | Capacitor, 10 μF, Tantalum | 1 |
| C3-C21 | Capacitor, 0.1 μF, Ceramic Chip | 17 |
| Z1 | A D 800/A D 802 | 1 |
| Z2 | 10H 116, ECL Line Receiver | 1 |

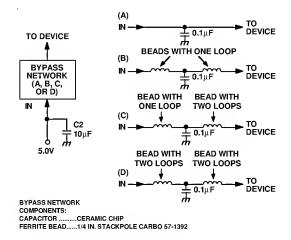


Figure 23. Bypass Network Schemes

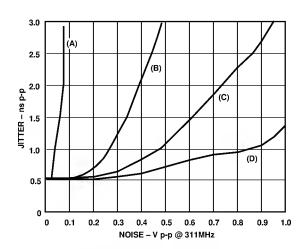


Figure 24. AD802-155 Output J itter vs. Supply Noise (PECL Configuration)

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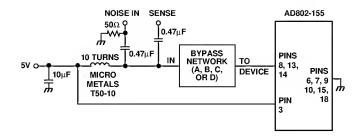


Figure 25. Power Supply Noise Sensitivity Test Circuit, PECL Configuration

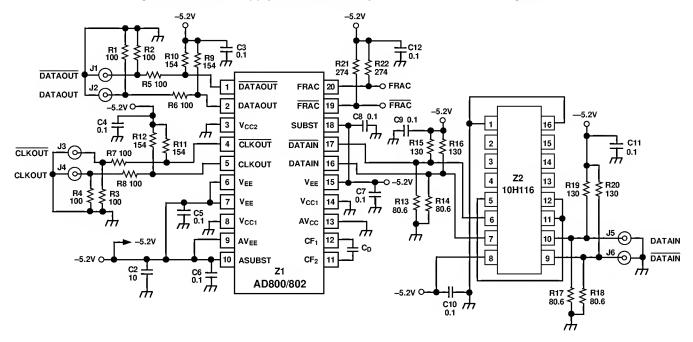


Figure 26. Evaluation Board Schematic, Negative Supply

Table II. Evaluation Board, Negative Supply: Components List

| Reference Designator | Description | Quantity |
|-------------------------|--|----------|
| R1-8 | Resistor, 100Ω , 1% | 8 |
| R9-12 | Resistor, 154 Ω , 1% | 4 |
| R13, 14, 17, 18 | Resistor, 80.6Ω , 1% | 4 |
| R15, 16, 19, 20 | Resistor, 130 Ω , 1% | 4 |
| R21, 22 | Resistor, 274 Ω , 1% | 2 |
| C_{D} | C apacitor, L oop D amping (See Specifications Page) | 1 |
| C 2 | C apacitor, 10 μF , T antalum | 1 |
| C 3-C 12 | Capacitor, 0.1 μF, Ceramic Chip | 10 |
| Z1 | AD 800/AD 802 | 1 |
| Z2 | 10H 116, ECL Line Receiver | 1 |

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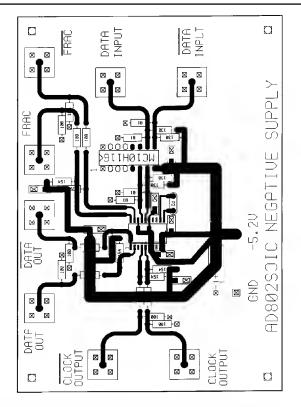


Figure 27. Negative Supply Configuration: Component Side (Top Layer)

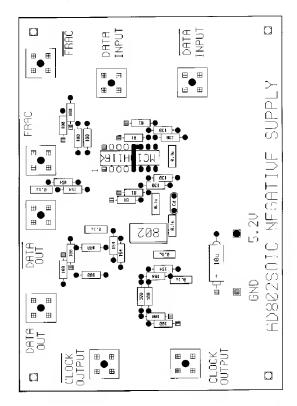


Figure 28. Negative Supply Configuration: Solder Side

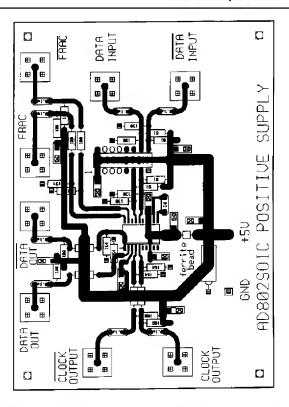


Figure 29. Positive Supply Configuration: Component Side (Top Layer)

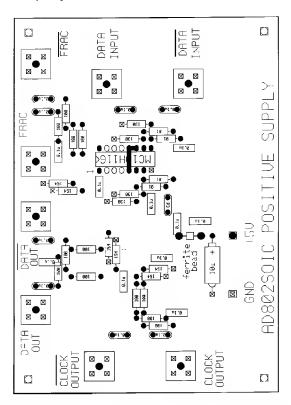


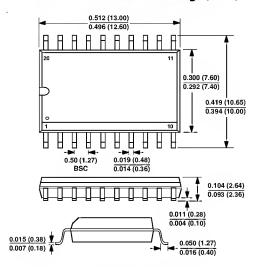
Figure 30. Positive Supply Configuration: Solder Side

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OUTLINE DIMENSIONS

Dimensions shown in inches and (mm).

20-Pin Small Outline IC Package (R-20)



20-Pin Cerdip Package (Q-20)

